

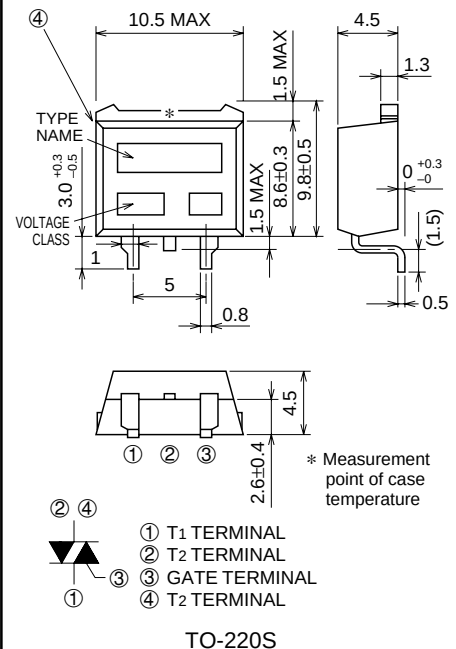
BCR12CS

MEDIUM POWER USE

NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

Refer to the page 6 as to the product guaranteed
maximum junction temperature 150°C**BCR12CS**

- I_T (RMS) **12A**
- V_{DRM} **600V**
- I_{FGT} I , I_{RGT} I , I_{RGT} III **20mA**

OUTLINE DRAWINGDimensions
in mm**APPLICATION**

Contactless AC switches, light dimmer, electric flasher unit,
control of household equipment such as TV sets · stereo · refrigerator · washing machine ·
infrared kotatsu · carpet · electric fan, solenoid drivers, small motor control,
copying machine, electric tool, other general purpose control applications

MAXIMUM RATINGS

Symbol	Parameter	Voltage class	Unit
		12	
V_{DRM}	Repetitive peak off-state voltage *1	600	V
V_{DSM}	Non-repetitive peak off-state voltage *1	720	V

Symbol	Parameter	Conditions	Ratings	Unit
I_T (RMS)	RMS on-state current	Commercial frequency, sine full wave 360° conduction, $T_c=98^\circ\text{C}$ *3	12	A
I_{TSM}	Surge on-state current	60Hz sinewave 1 full cycle, peak value, non-repetitive	120	A
I^2_t	I^2_t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	60	A ² s
PGM	Peak gate power dissipation		5	W
PG (AV)	Average gate power dissipation		0.5	W
VGM	Peak gate voltage		10	V
IGM	Peak gate current		2	A
T_j	Junction temperature		-40 ~ +125	°C
T_{stg}	Storage temperature		-40 ~ +125	°C
—	Weight	Typical value	1.2	g

*1. Gate open.

Mar. 2002

BCR12CS

Refer to the page 6 as to the product guaranteed
maximum junction temperature 150°C

MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IdRM	Repetitive peak off-state current	T _j =125°C, V _{DRM} applied	—	—	2.0	mA
V _{TM}	On-state voltage	T _c =25°C, I _{TM} =20A, Instantaneous measurement	—	—	1.6	V
V _{FGT} I	Gate trigger voltage *2	T _j =25°C, V _D =6V, R _L =6Ω, R _G =330Ω	—	—	1.5	V
V _{RGT} I			—	—	1.5	V
V _{RGT} III			—	—	1.5	V
I _{FGT} I	Gate trigger current *2	T _j =25°C, V _D =6V, R _L =6Ω, R _G =330Ω	—	—	20	mA
I _{RGT} I			—	—	20	mA
I _{RGT} III			—	—	20	mA
V _{GD}	Gate non-trigger voltage	T _j =125°C, V _D =1/2V _{DRM}	0.2	—	—	V
R _{th} (j-c)	Thermal resistance	Junction to case *3 *4	—	—	1.8	°C/W
(dv/dt) _c	Critical-rate of rise of off-state commutating voltage *5	T _j =125°C	10	—	—	V/μs

*2. Measurement using the gate trigger characteristics measurement circuit.

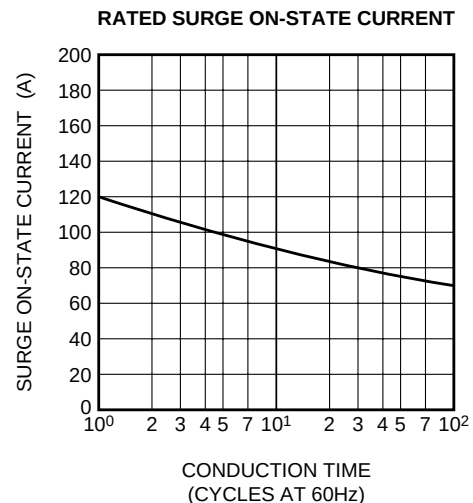
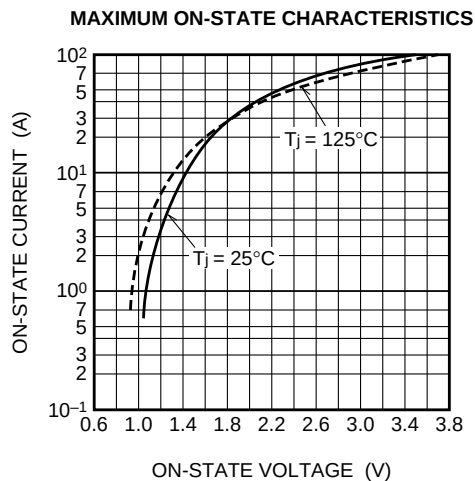
*3. Case temperature is measured on the T2 terminal.

*4. The contact thermal resistance R_{th} (c-j) in case of greasing is 1.0°C/W.

*5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature T _j =125°C 2. Rate of decay of on-state commutating current (di/dt) _c =-6.0A/ms 3. Peak off-state voltage V _D =400V	

PERFORMANCE CURVES

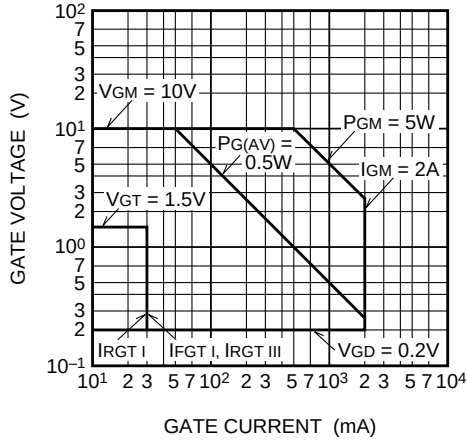


BCR12CS

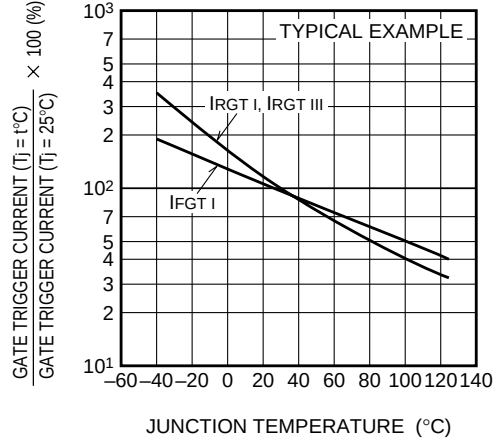
Refer to the page 6 as to the product guaranteed
maximum junction temperature 150°C

MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

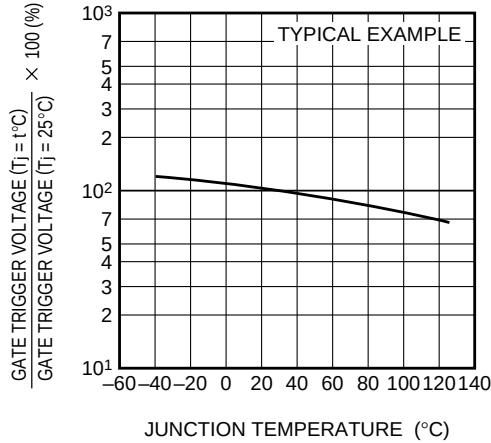
**GATE CHARACTERISTICS
(I, II AND III)**



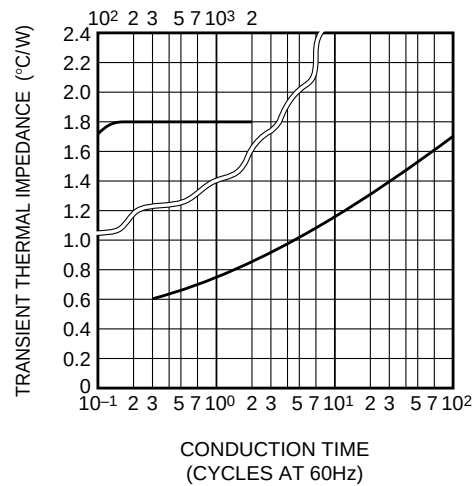
**GATE TRIGGER CURRENT VS.
JUNCTION TEMPERATURE**



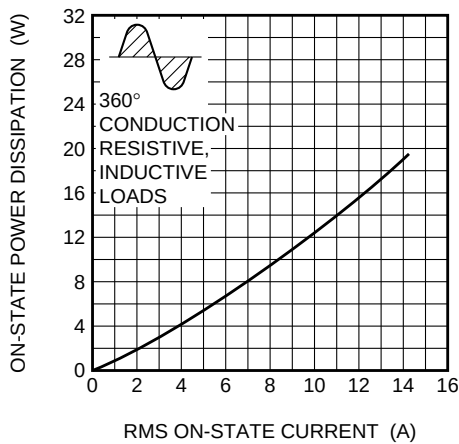
**GATE TRIGGER VOLTAGE VS.
JUNCTION TEMPERATURE**



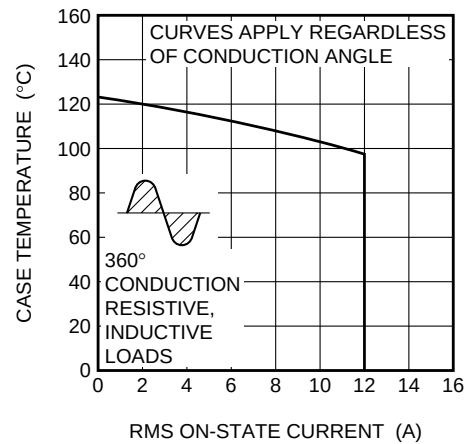
**MAXIMUM TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(JUNCTION TO CASE)**



**MAXIMUM ON-STATE POWER
DISSIPATION**



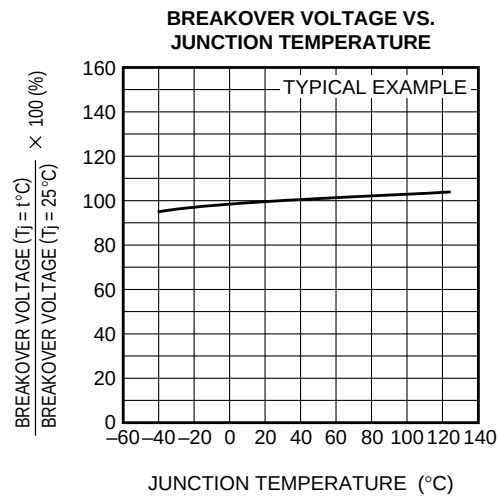
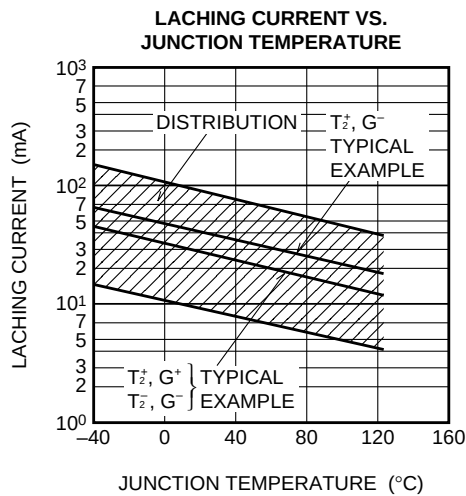
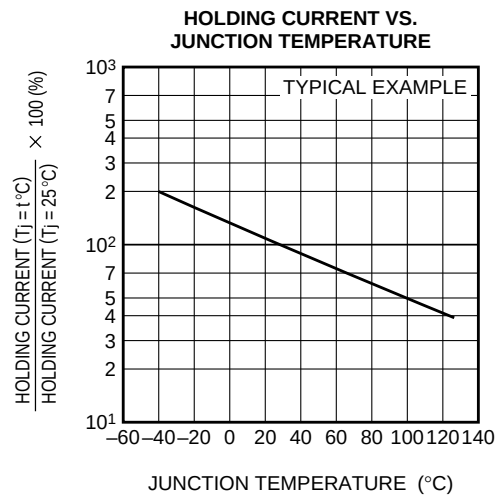
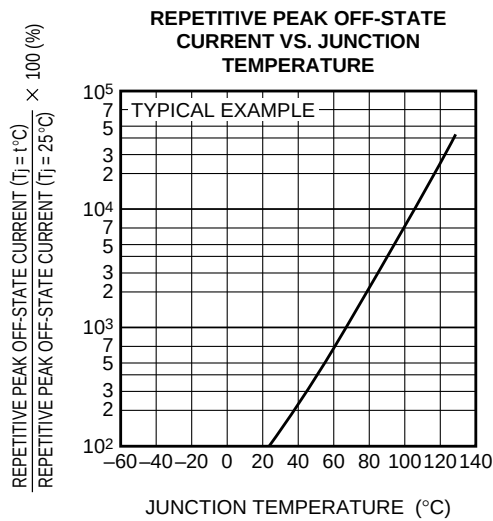
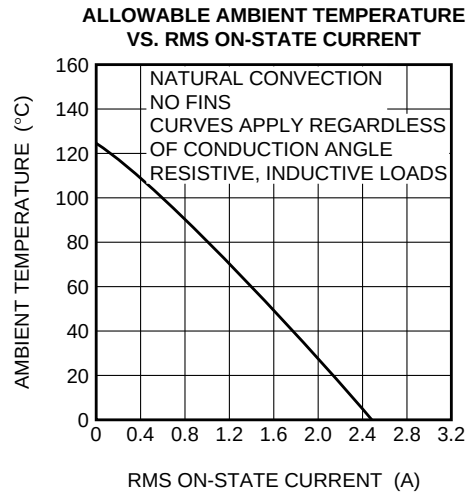
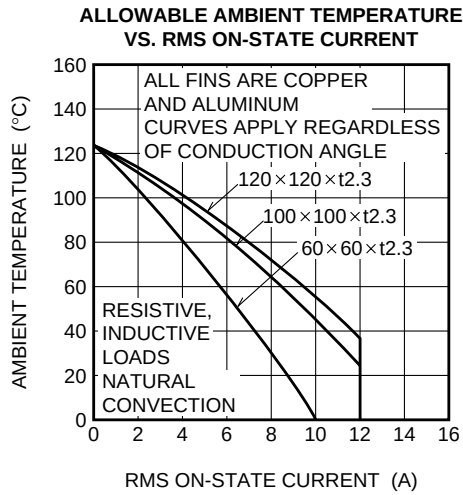
**ALLOWABLE CASE TEMPERATURE
VS. RMS ON-STATE CURRENT**



BCR12CS

Refer to the page 6 as to the product guaranteed
maximum junction temperature 150°C

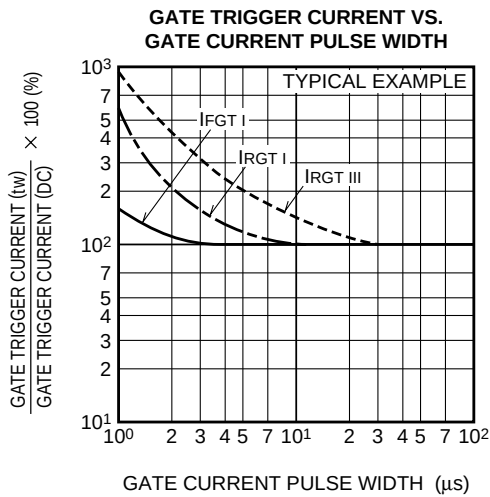
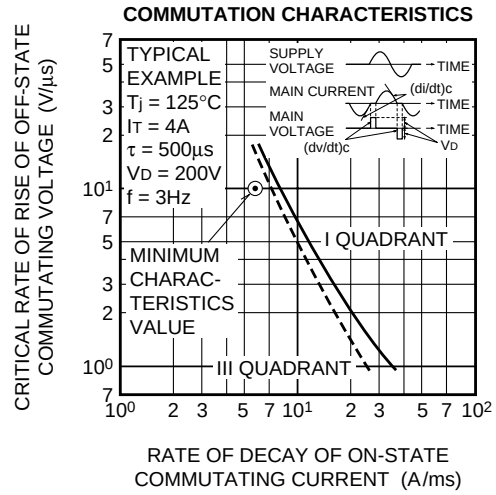
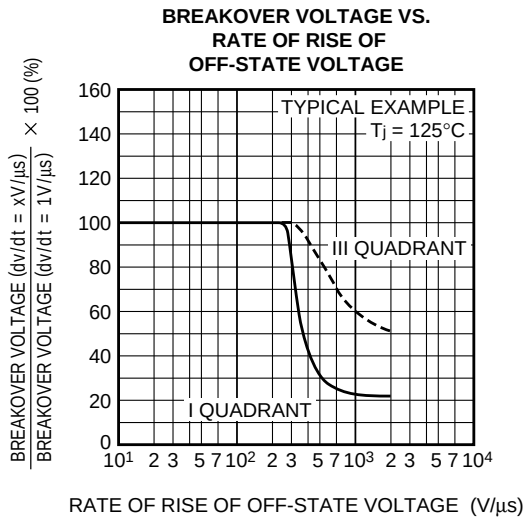
MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE



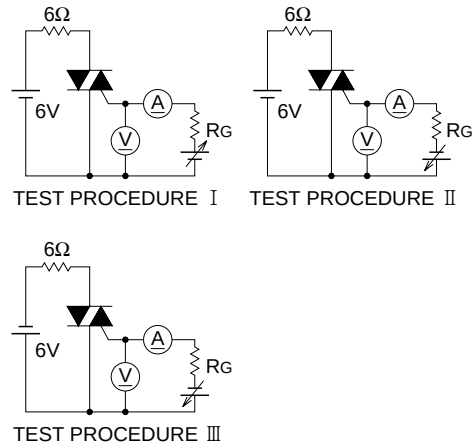
BCR12CS

Refer to the page 6 as to the product guaranteed maximum junction temperature 150°C

MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE



GATE TRIGGER CHARACTERISTICS TEST CIRCUITS



BCR12CS

The product guaranteed maximum junction temperature 150°C (See warning.)

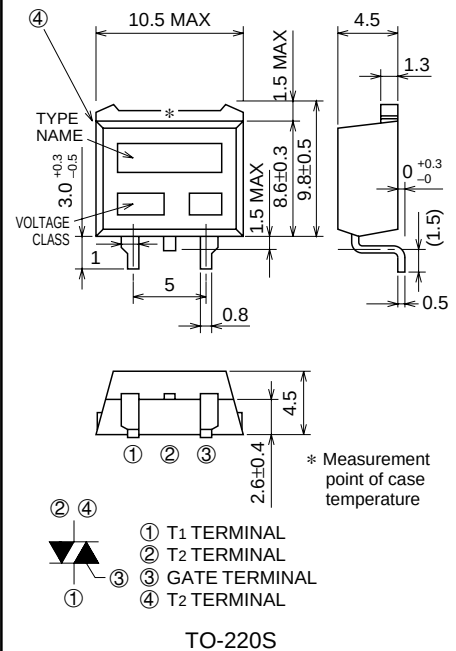
MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

BCR12CS

- **IT (RMS)** **12A**
- **VDRM** **600V**
- **IFGT I , IRGT I , IRGT III** **20mA**

OUTLINE DRAWING

Dimensions
in mm

**APPLICATION**

Contactless AC switches, light dimmer, electric flasher unit,
control of household equipment such as TV sets · stereo · refrigerator · washing machine ·
infrared kotatsu · carpet · electric fan, solenoid drivers, small motor control,
copying machine, electric tool, other general purpose control applications

(Warning)

1. Refer to the recommended circuit values around the triac before using.
2. Be sure to exchange the specification before using. If not exchanged, general triacs will be supplied.

MAXIMUM RATINGS

Symbol	Parameter	Voltage class	Unit
		12	
VDRM	Repetitive peak off-state voltage *1	600	V
VDSM	Non-repetitive peak off-state voltage *1	720	V

Symbol	Parameter	Conditions	Ratings	Unit
IT (RMS)	RMS on-state current	Commercial frequency, sine full wave 360° conduction, T _c =123°C *3	12	A
ITSM	Surge on-state current	60Hz sinewave 1 full cycle, peak value, non-repetitive	120	A
I ² _t	I ² _t for fusing	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current	60	A ² s
PGM	Peak gate power dissipation		5	W
PG (AV)	Average gate power dissipation		0.5	W
VGM	Peak gate voltage		10	V
IGM	Peak gate current		2	A
T _j	Junction temperature		-40 ~ +150	°C
T _{stg}	Storage temperature		-40 ~ +150	°C
—	Weight	Typical value	1.2	g

*1. Gate open.

BCR12CS

The product guaranteed maximum junction temperature 150°C (See warning.)

MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
IdRM	Repetitive peak off-state current	T _j =150°C, V _{DRM} applied	—	—	2.0	mA
V _{TM}	On-state voltage	T _c =25°C, I _{TM} =20A, Instantaneous measurement	—	—	1.6	V
V _{FGT} I	Gate trigger voltage *2	T _j =25°C, V _D =6V, R _L =6Ω, R _G =330Ω	—	—	1.5	V
V _{RGT} I			—	—	1.5	V
V _{RGT} III			—	—	1.5	V
I _{FGT} I	Gate trigger current *2	T _j =25°C, V _D =6V, R _L =6Ω, R _G =330Ω	—	—	20	mA
I _{RGT} I			—	—	20	mA
I _{RGT} III			—	—	20	mA
V _{GD}	Gate non-trigger voltage	T _j =125°C/150°C, V _D =1/2V _{DRM}	0.2/0.1	—	—	V
R _{th} (j-c)	Thermal resistance	Junction to case *3 *4	—	—	1.8	°C/W
(dv/dt) _c	Critical-rate of rise of off-state commutating voltage *5	T _j =125°C/150°C	10/1	—	—	V/μs

*2. Measurement using the gate trigger characteristics measurement circuit.

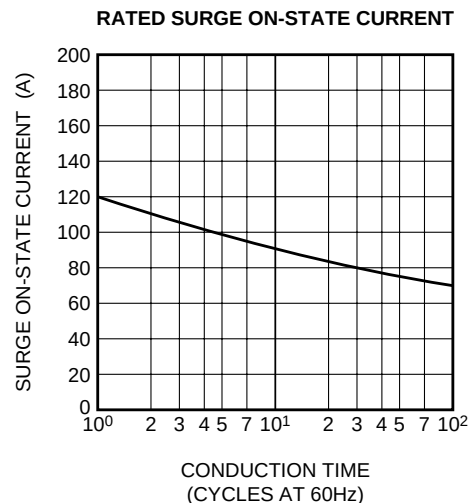
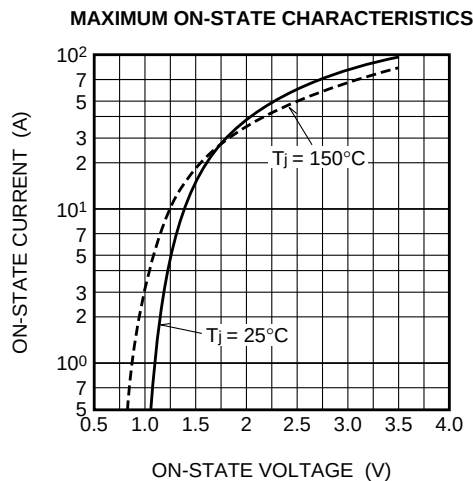
*3. Case temperature is measured on the T2 terminal.

*4. The contact thermal resistance R_{th} (c-j) in case of greasing is 1.0°C/W.

*5. Test conditions of the critical-rate of rise of off-state commutating voltage is shown in the table below.

Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature T _j =125°C/150°C 2. Rate of decay of on-state commutating current (di/dt) _c =-6.0A/ms 3. Peak off-state voltage V _D =400V	

PERFORMANCE CURVES

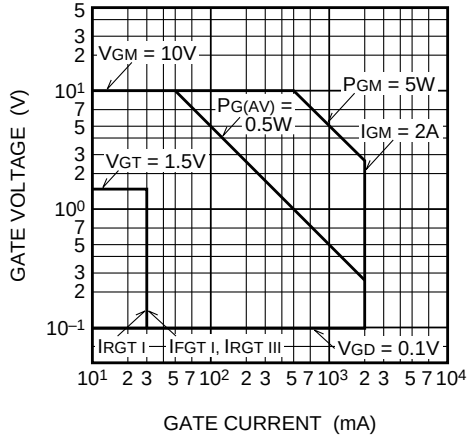


BCR12CS

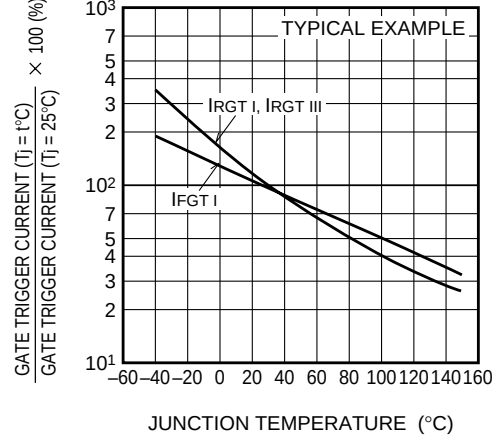
The product guaranteed maximum junction temperature 150°C (See warning.)

MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

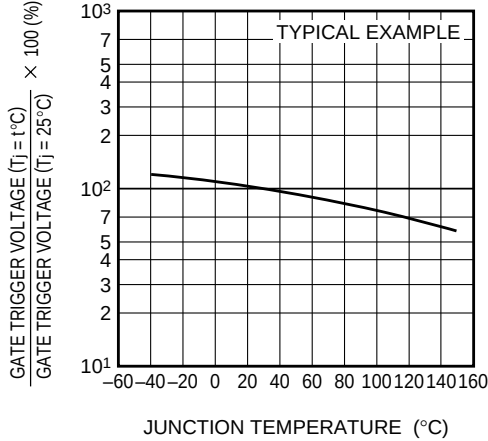
**GATE CHARACTERISTICS
(I, II AND III)**



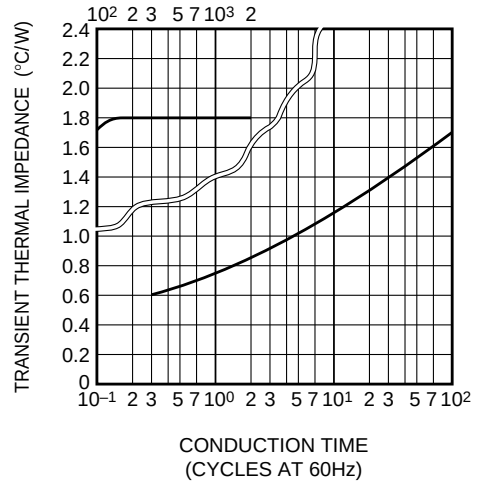
**GATE TRIGGER CURRENT VS.
JUNCTION TEMPERATURE**



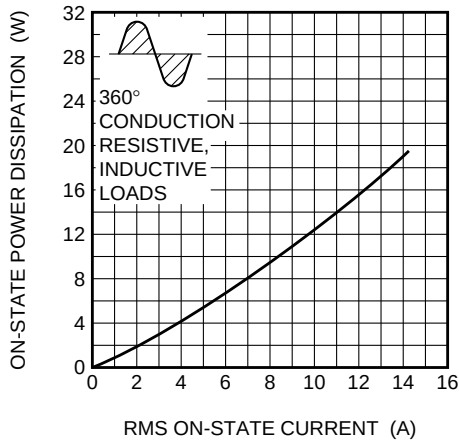
**GATE TRIGGER VOLTAGE VS.
JUNCTION TEMPERATURE**



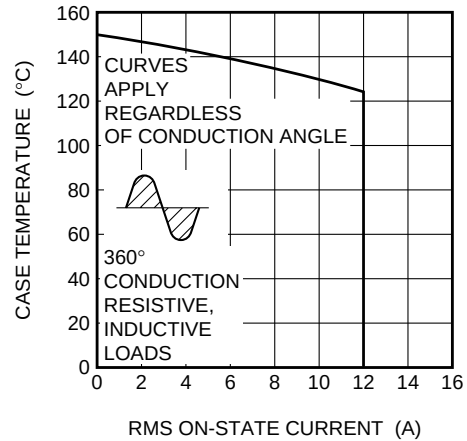
**MAXIMUM TRANSIENT THERMAL
IMPEDANCE CHARACTERISTICS
(JUNCTION TO CASE)**



**MAXIMUM ON-STATE POWER
DISSIPATION**



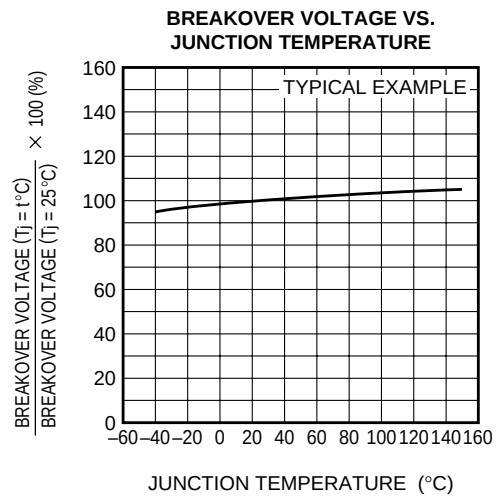
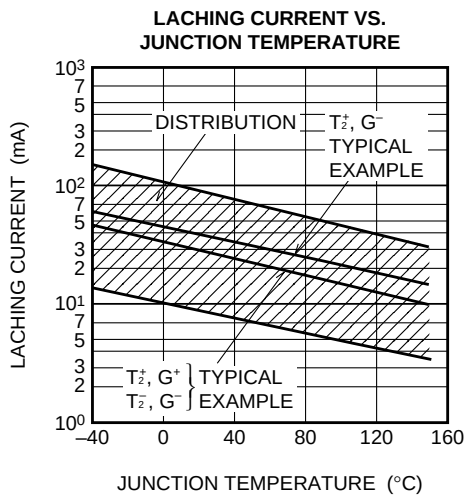
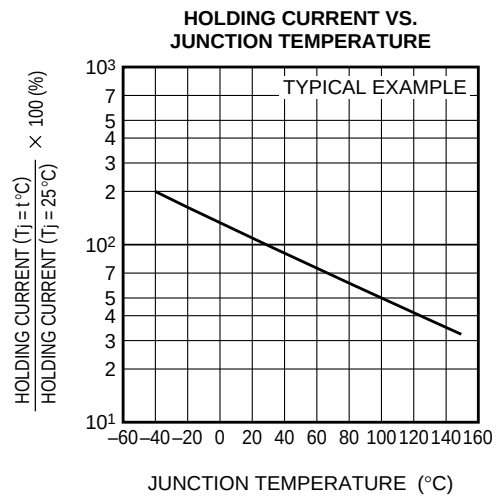
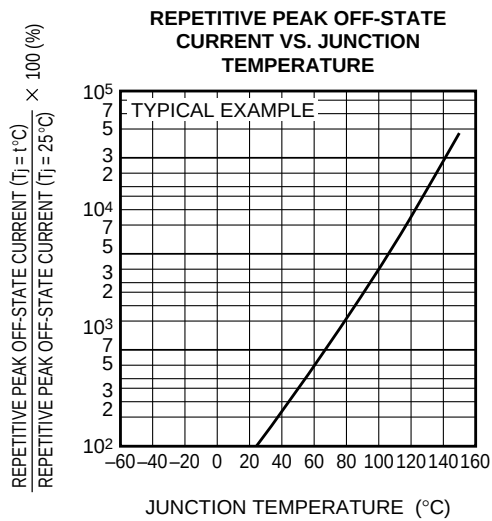
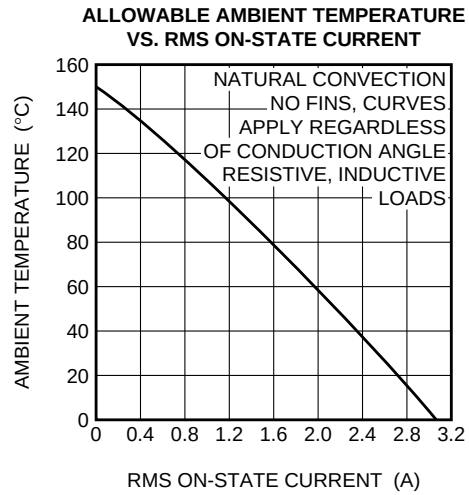
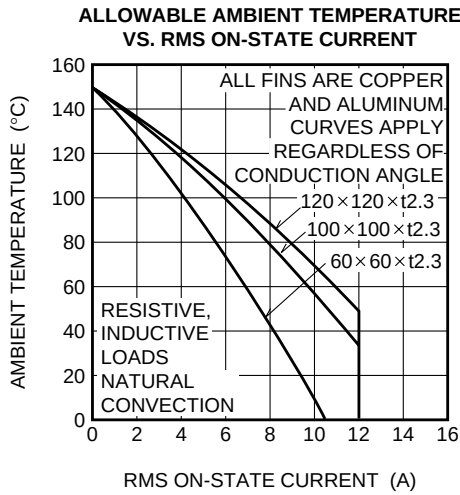
**ALLOWABLE CASE TEMPERATURE
VS. RMS ON-STATE CURRENT**



BCR12CS

The product guaranteed maximum junction temperature 150°C (See warning.)

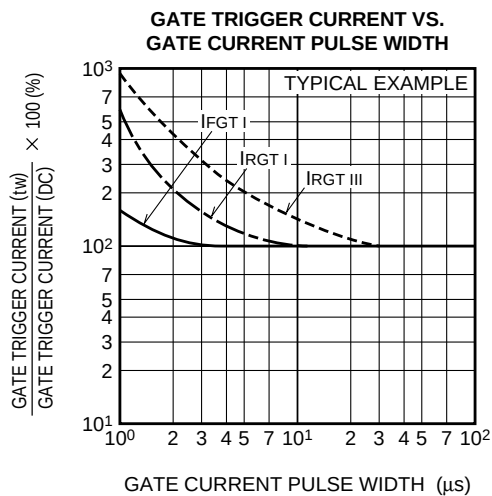
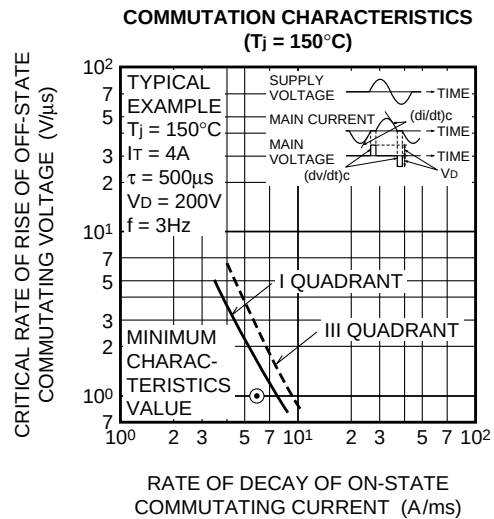
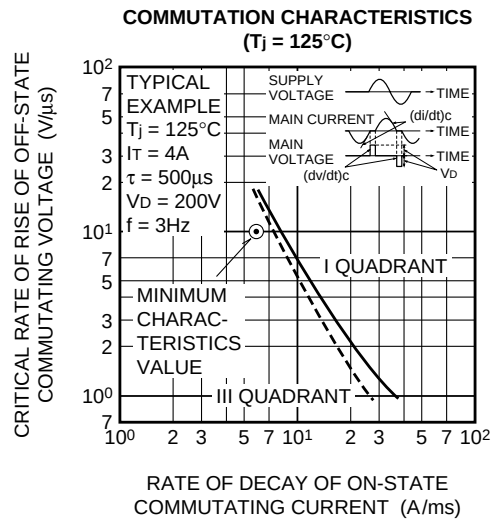
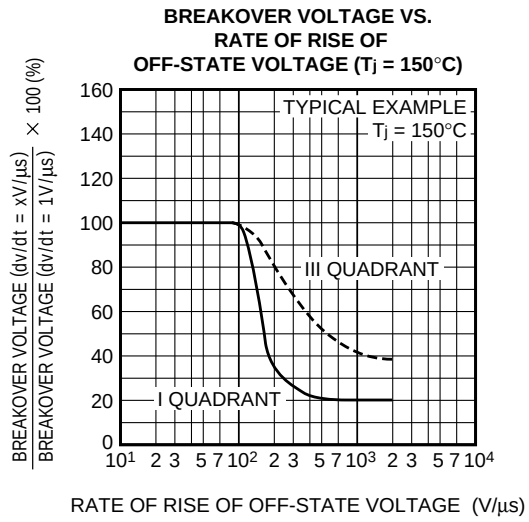
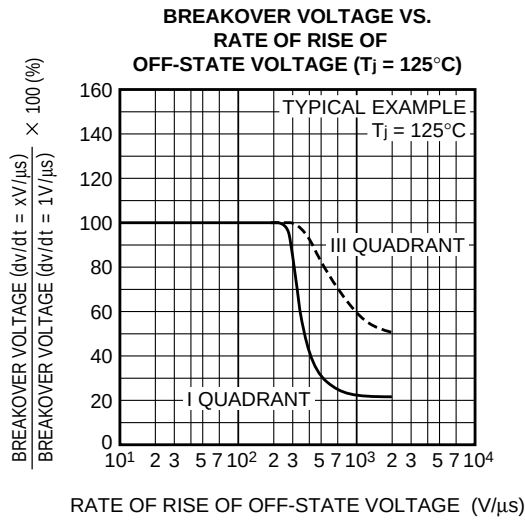
MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE



BCR12CS

The product guaranteed maximum junction temperature 150°C (See warning.)

MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

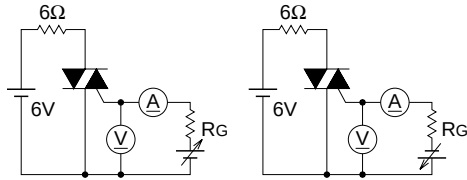


BCR12CS

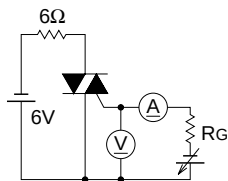
The product guaranteed maximum junction temperature 150°C (See warning.)

MEDIUM POWER USE
NON-INSULATED TYPE, PLANAR PASSIVATION TYPE

GATE TRIGGER CHARACTERISTICS TEST CIRCUITS

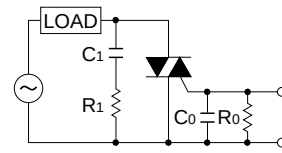


TEST PROCEDURE I TEST PROCEDURE II



TEST PROCEDURE III

RECOMMENDED CIRCUIT VALUES AROUND THE TRIAC



$C_1 = 0.1 \sim 0.47 \mu\text{F}$ $C_0 = 0.1 \mu\text{F}$
 $R_1 = 47 \sim 100 \Omega$ $R_0 = 100 \Omega$